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CORRECTION



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Correction: Direct synthesis of large-scale hierarchical MoS₂ films nanostructured with orthogonally oriented vertically and horizontally aligned layers

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Correction for 'Direct synthesis of large-scale hierarchical MoS₂ films nanostructured with orthogonally oriented vertically and horizontally aligned layers' by Xiaoyan Zhang *et al.*, *Nanoscale*, 2016, DOI: 10.1039/ c5nr05938k.

The authors would like to make an amendment to line 58 (right column) on page 4 of their article. The term "(5.7 for 6 h, and 5.4 for 8 h)" should read "(0.57 for 6 h, and 0.54 for 8 h)".

The authors also wish to correct the term " $(NH_2)_2S$ " to " $(NH_2)_2CS$ " in the sentence beginning "Here, $(NH_4)_2MoO_4$ and..." in line 12 on page 3 and in Fig. 1 of the original paper.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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